Product data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882T leadless ultra small plastic SMD package.

1.2 Features

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

RF attenuators and switches

2. Pinning information

| Table 1. | Discrete pinning |
|----------|------------------|
| Din | Description |

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|----------------------|-----------------|
| 1 | cathode | [1] | |
| 2 | anode | Transparent top view | ↓ sym006 |

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 2. Ordering information

| Type number | Package | Package | | | | |
|-------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| BAP1321LX | - | leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm | SOD882T | | | |





4. Marking

Table 3. Marking

| Type number | Marking code |
|-------------|--------------|
| BAP1321LX | LH |

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--------------------------|-----|------|------|
| V_R | reverse voltage | | - | 60 | V |
| I _F | forward current | | - | 100 | mA |
| P _{tot} | total power dissipation | $T_{sp} = 90 ^{\circ}C$ | - | 130 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | -65 | +150 | °C |

6. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | 74 | K/W |

7. Characteristics

Table 6. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------------------|--------------------------|-------------------------------------|-----|------|-----------------------|------|
| V_{F} | forward voltage | $I_F = 50 \text{ mA}$ | - | 0.95 | 1.1 | V |
| I _R | reverse current | V _R = 60 V | - | - | 100 | nA |
| C _d | diode capacitance | see Figure 1; f = 1 MHz; | | | | |
| | | $V_R = 0 V$ | - | 0.32 | - | pF |
| | | V _R = 1 V | - | 0.27 | 0.38 | pF |
| | | V _R = 20 V | - | 0.21 | 0.28 | pF |
| r _D | diode forward resistance | see Figure 2; f = 100 MHz; | | | | |
| | | $I_F = 0.5 \text{ mA}$ | - | 3.3 | 5.0 | Ω |
| | | I _F = 1 mA | - | 2.4 | 3.6 | Ω |
| | | I _F = 10 mA | - | 1.2 | 1.8 | Ω |
| | | I _F = 100 mA | - | 0.9 | 1.3 | Ω |
| ISL | isolation | see Figure 3; V _R = 0 V; | | | | |
| | | f = 900 MHz | - | 17 | - | dB |
| | | f = 1800 MHz | - | 12 | - | dB |
| | | f = 2450 MHz | - | 10 | - | dB |
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Table 6. Characteristics ... continued $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|--------------------------|--|-----|------|-----|------|
| L _{ins} | insertion loss | see Figure 4; $I_F = 0.5 \text{ mA}$; | | | | |
| | | f = 900 MHz | - | 0.25 | - | dB |
| | | f = 1800 MHz | - | 0.26 | - | dB |
| | | f = 2450 MHz | - | 0.27 | - | dB |
| L _{ins} | insertion loss | see Figure 4; I _F = 1 mA; | | | | |
| | | f = 900 MHz | - | 0.19 | - | dB |
| | | f = 1800 MHz | - | 0.20 | - | dB |
| | | f = 2450 MHz | - | 0.21 | - | dB |
| L _{ins} | insertion loss | see Figure 4; I _F = 10 mA; | | | | |
| | | f = 900 MHz | - | 0.11 | - | dB |
| | | f = 1800 MHz | - | 0.13 | - | dB |
| | | f = 2450 MHz | - | 0.14 | - | dB |
| L _{ins} | insertion loss | see Figure 4; I _F = 100 mA; | | | | |
| | | f = 900 MHz | - | 0.09 | - | dB |
| | | f = 1800 MHz | - | 0.11 | - | dB |
| | | f = 2450 MHz | - | 0.12 | - | dB |
| τ _L | charge carrier life time | when switched from I $_{\!F}$ = 10 mA to I $_{\!R}$ = 6 mA; R $_{\!L}$ = 100 $\Omega;$ measured at I $_{\!R}$ = 3 mA | - | 0.48 | - | μs |
| - S | series inductance | I _F = 100 mA; f = 100 MHz | - | 0.4 | - | nΗ |

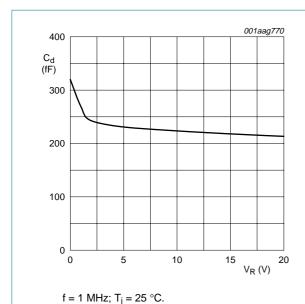


Fig 1. Diode capacitance as a function of reverse voltage; typical values

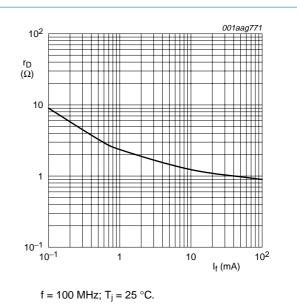
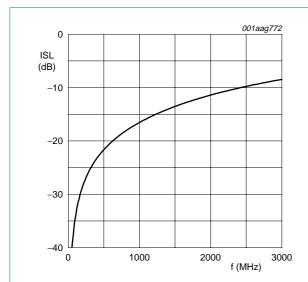
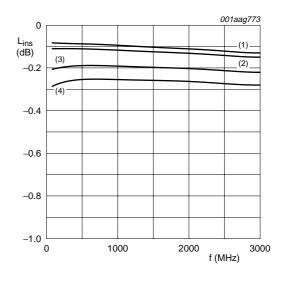


Fig 2. Forward resistance as a function of forward current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Diode zero biased and inserted in series with a 50 Ω stripline circuit



 $T_{amb} = 25 \, ^{\circ}C$

- (1) $I_F = 100 \text{ mA}$
- (2) $I_F = 10 \text{ mA}$
- (3) $I_F = 1 \text{ mA}$
- (4) $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network

Fig 4. Insertion loss of the diode as a function of frequency; typical values

8. Package outline

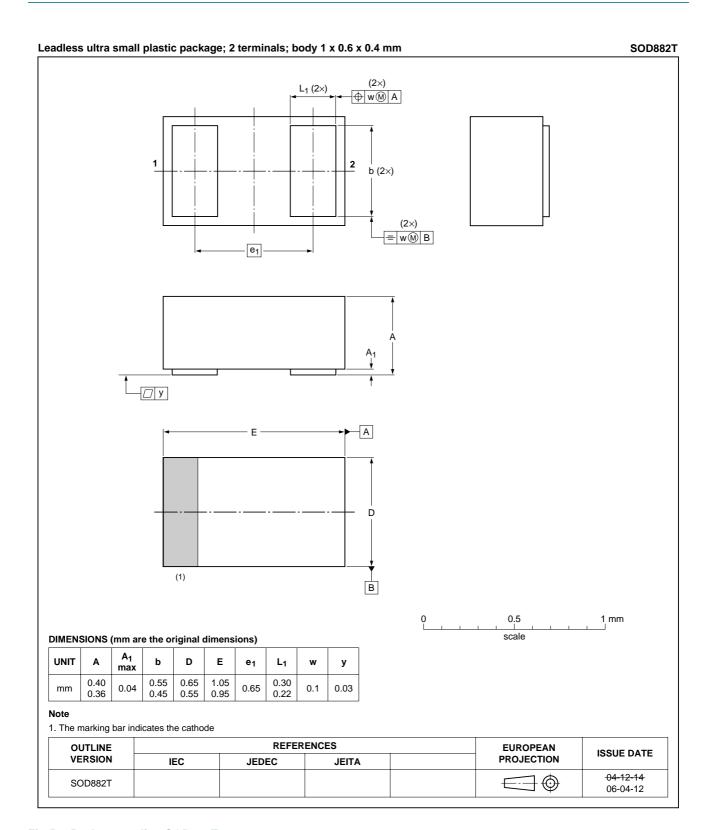


Fig 5. Package outline SOD882T



9. Abbreviations

Table 7. Abbreviations

| Acronym | Description |
|---------|---------------------------|
| PIN | P-type, Intrinsic, N-type |
| SMD | Surface Mounted Device |
| RF | Radio Frequency |

10. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| BAP1321LX_1 | 20070730 | Product data sheet | - | - |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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- [1] Please consult the most recently issued document before initiating or completing a design.
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